

SSC8030GS1

N-Channel Enhancement Mode MOSFET

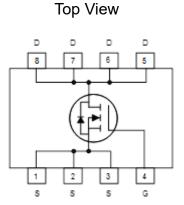
> Features

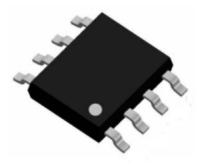
VDS	VGS	RDSON Typ.	ID
30V	1001/	9mR@10V	124
	±20V	11mR@4V5	13A

> Description

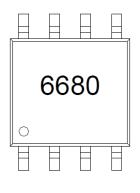
This device uses advanced trench technology to provide excellent RDSON and low gate charge. This device is suitable for use as a load switch or in PWM applications.

Pin configuration





SOP-8



Marking

> Applications

- Load Switch
- NB/PC
- DCDC conversion

> Ordering Information

Device	Package	Shipping
SSC8030GS1	SOP-8	4000/Reel

> Absolute Maximum Ratings(T_A=25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
V _{DSS}	Drain-to-Source Voltage	30	V
V _{GSS}	Gate-to-Source Voltage	±20	V
I _D	Continuous Drain Current ^a	13	А
I _{DM}	Pulsed Drain Current ^b	51	А
PD	Power Dissipation ^c	6	W
P _{DSM}	Power Dissipation ^a	2.5	W
I _{AS}	Avalanche Current ^b L=0.5mH Single Pulse	19	А
E _{AS}	Avalanche Energy ^b L=0.5mH Single Pulse	90	mJ
TJ	Operation junction temperature	-55 to 150	°C
T _{STG}	Storage temperature range	-55 to 150	°C

> **Thermal Resistance Ratings**($T_A=25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Ratings	Unit
R _{θJA}	Junction-to-Ambient Thermal Resistance ^a	45	°C/W
R _{eJC}	Junction-to-Case Thermal Resistance	20	°C/W

Note:

- a. The value of RθJA is measured with the device mounted on 1 in² FR-4 board with 2oz.copper,in a still air environment with TA=25°C.The value in any given application depends on the user is specific board design. The current rating is based on the t≤ 10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation PD is based on TJ(MAX)=150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

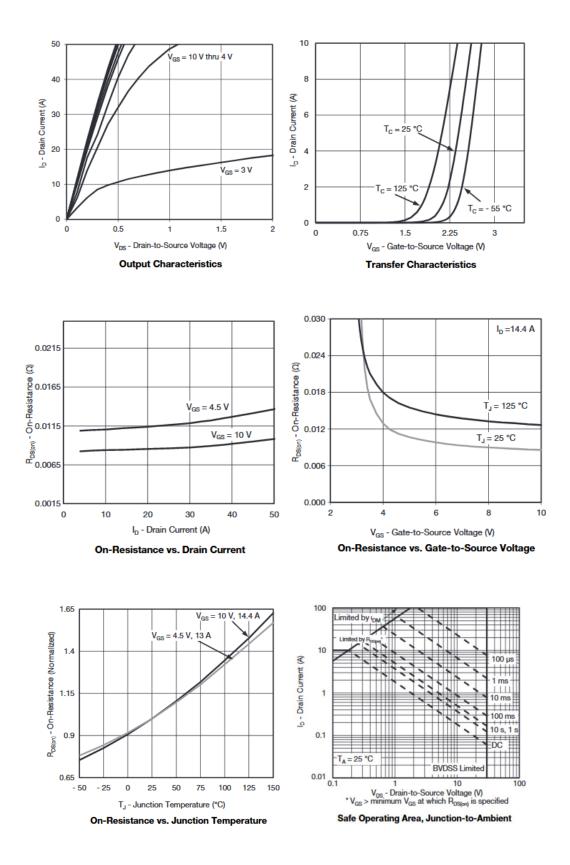


> Electronics Characteristics(T_A=25°C unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур.	Мах	Unit	
V _{(BR)DSS}	Drain-Source Breakdown Voltage	VGS=0V,ID=250uA	30			V	
$V_{GS \ (th)}$	Gate Threshold Voltage	VDS=VGS,ID=250uA	1		3	V	
	Drain-Source On-	VGS=10V,ID=15A		9	11	(
R _{DS(on)}	Resistance	VGS=4.5V,ID=12A		11	15	mR	
I _{DSS}	Zero Gate Voltage Drain Current	VDS=24V,VGS=0V			1	uA	
I _{GSS}	Gate-Source leak current	VGS=±20V,VDS=0V			±100	nA	
G _{FS}	Transconductance	VDS=15V,ID=12A		46		S	
V _{SD}	Forward Voltage	VGS=0V,IS=1A		0.8	1.5	V	
Ciss	Input Capacitance			1200			
Coss	Output Capacitance	VDS=15V, VGS=0V,f=1MHz		200		pF	
Crss	Reverse Transfer Capacitance			105			
T _{D(ON)}	Turn-on delay time			18			
Tr	Rise time	VGS=10V,		6			
T _{D(OFF)}	Turn-off delay time	VDS=15V, RL=2.3R, RG=3R		70		ns	
Tf	Fall time			17			
Qg	Total Gate charge			20			
Qgs	Gate to Source charge	VGS=10V, VDS=10V, ID=14A		3		nC	
Qgd	Gate to Drain charge			5			

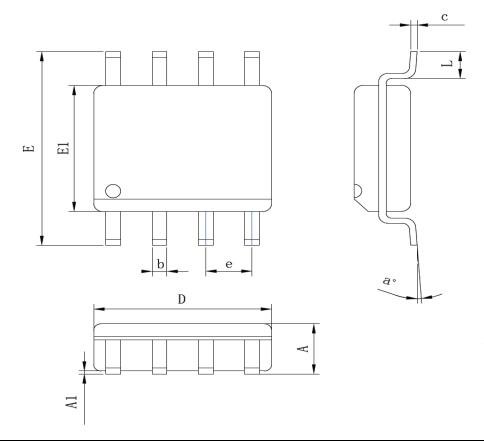


> Typical Characteristics(T_A=25°C unless otherwise noted)





Package Information



SYMBOL	MILLIMETER			
	MIN	NOM	MAX	
A			1.75	
A1	0.10		0.23	
b	0.35		0.48	
с	0.19		0.25	
D	4.70	4.90	5.10	
E	5.80	6.00	6.20	
E1	3.70	3.9	4.10	
е	1.27BSC			
L	0.50	0.80		
a°	0°		8°	



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